

ISSUE CLASSIFICATION	
Class	Subclass

FILED UNDER 35 U.S.C. 371

PATENT NUMBER

U.S. UTILITY Patent Application

CP	O.I.P.E.	PATENT DATE
SCANNED	TDY Q.A. KC	

APPLICATION NO. 09/786059	CONT/PRIOR D	CLASS 427	SUBCLASS 2	ART UNIT 1762	EXAMINER <i>Len</i>
APPLICANTS Pascale Motte Joaquim Torres Brigitte Descouts Jean Palleau	TITLE Method for depositing a silicon-containing dielectric material on copper				

PTO-20
12/99

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ISSUING CLASSIFICATION												
ORIGINAL				CROSS REFERENCE(S)								
CLASS		SUBCLASS		CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)							
INTERNATIONAL CLASSIFICATION												

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<input type="checkbox"/> TERMINAL DISCLAIMER	DRAWINGS			CLAIMS ALLOWED	
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.
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<input type="checkbox"/> The terminal _____ months of this patent have been disclaimed.	_____ (Legal Instruments Examiner) (Date)			ISSUE BATCH NUMBER	
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